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	Substitute for	form 1449B/PTO	4		Complete if Known		
					Application Number	10/599,106	
INFORMATION DISCLOSURE					Filing Date	09/19/2006	
	STAT	EMENT BY A	APPLI	CANT	First Named Inventor	Ji Zhu	
					Art Unit	2812	
		(Use as many sheets as	necessary)	}	Examiner Name	Unknown	
	Sheet	1	of	2	Attorney Docket Number	IB-1997	

NON PATENT LITERATURE DOCUMENTS						
Examiner Initials*	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T²			
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Examiner	Date	
Signature	Considered	<u></u>

<sup>\*</sup>EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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	INFO STAT	STATEMENT BY	INFORMATION DISCLOS STATEMENT BY APPLIC	INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use as many sheets as necessary)	INFORMATION DISCLOSURE STATEMENT BY APPLICANT  (Use as many sheets as necessary)  Application Number  Filing Date  First Named Inventor  Art Unit  Examiner Name	Application Number   10/599,106	

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		HAHM, ET AL., "Direct Ultrasensitive Electrical Detection of DNA and DNA Sequence Variations using Nanowire Nanosensors," Nano Letters, Vol. 4 (No. 1), p. 51-54, (2004).				
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